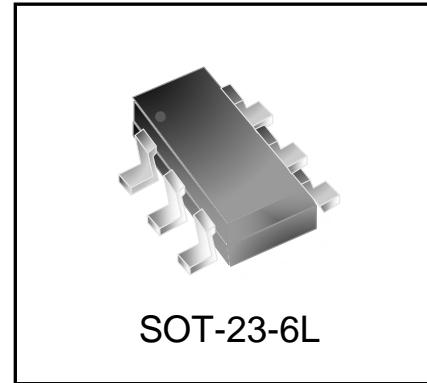


Features

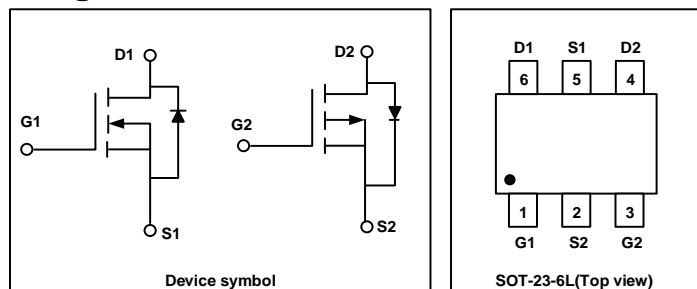
- Way-on Small Signal MOSFETs
- N - Channel:
 - $V_{DS} = 30V, I_D = 3.4A$
 - $R_{DS(on)} < 30m\Omega @ V_{GS} = 10V$
 - $R_{DS(on)} < 50m\Omega @ V_{GS} = 4.5V$
- P - Channel:
 - $V_{DS} = -30V, I_D = -2.3A$
 - $R_{DS(on)} < 84m\Omega @ V_{GS} = -10V$
 - $R_{DS(on)} < 118m\Omega @ V_{GS} = -4.5V$
- Trench LV MOSFET Technology



Mechanical Characteristics

- SOT-23-6L Package
- Marking : Making Code
- RoHS Compliant & Halogen-Free

Schematic & PIN Configuration



Absolute Maximum Ratings ($T_A=25^\circ C$ unless otherwise noted)

| Parameter | Symbol | Value | | Unit |
|--------------------------------------------------|----------------|------------|----------|------------|
| Drain-Source Voltage | V_{DS} | 30 | -30 | V |
| Gate-Source Voltage | V_{GS} | ± 20 | ± 20 | V |
| Continuous Drain Current | I_D | 3.4 | -2.3 | A |
| Pulsed Drain Current ¹ | I_{DM} | 13.6 | -9.2 | A |
| Power Dissipation | P_D | 1.2 | | W |
| Operating Junction and Storage Temperature Range | T_J, T_{STG} | -55 to 150 | | $^\circ C$ |

Thermal Characteristics

| Parameter | Symbol | Value | Unit |
|----------------------------------------------------------|-----------------|-------|--------------|
| Thermal Resistance from Junction to Ambient ² | $R_{\theta JA}$ | 104 | $^\circ C/W$ |

Electrical Characteristics N-Channel ($T_J=25^\circ\text{C}$ unless otherwise noted)

| Parameter | Symbol | Test Condition | Min. | Typ. | Max. | Unit |
|-----------------------------------------------|--------------|-------------------------------------------------------------|------|------|-----------|------------|
| Static Characteristics | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | $V_{GS} = 0V, I_D = 250\mu A$ | 30 | - | - | V |
| Gate-body Leakage Current | I_{GSS} | $V_{DS} = 0V, V_{GS} = \pm 20V$ | - | - | ± 100 | nA |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 30V, V_{GS} = 0V$ | - | - | 1 | μA |
| Gate threshold voltage | $V_{GS(th)}$ | $V_{DS} = V_{GS}, I_D = 250\mu A$ | 1.0 | 1.5 | 2 | V |
| Drain-Source On-state Resistance ³ | $R_{DS(on)}$ | $V_{GS} = 10V, I_D = 3.4A$ | - | 24 | 30 | m Ω |
| | | $V_{GS} = 4.5V, I_D = 2A$ | - | 38 | 50 | |
| Dynamic Characteristics⁴ | | | | | | |
| Input Capacitance | C_{iss} | $V_{GS} = 0V, V_{DS} = 15V,$ $f = 1MHz$ | - | 230 | - | pF |
| Output Capacitance | C_{oss} | | - | 43 | - | |
| Reverse Transfer Capacitance | C_{rss} | | - | 34 | - | |
| Switching Characteristics⁴ | | | | | | |
| Total gate charge | Q_{gt} | $V_{GS}=10V, V_{DS}=15V,$ $I_D= 3.4A$ | - | 6 | - | nC |
| Gate-source charge | Q_{gs} | | - | 0.8 | - | |
| Gate-drain charge | Q_{gd} | | - | 1.1 | - | |
| Turn-On Delay Time | $t_{d(on)}$ | $V_{GS}= 10V, V_{DD} = 15V,$ $R_G = 3\Omega, I_D = 3.4A$ | - | 7 | - | ns |
| Turn-On Rise Time | t_r | | - | 12 | - | |
| Turn-Off Delay Time | $t_{d(off)}$ | | - | 14 | - | |
| Turn- Off Fall Time | t_f | | - | 6 | - | |
| Source-Drain Diode characteristics | | | | | | |
| Body Diode Voltage ³ | V_{SD} | $I_S = 1A, V_{GS} = 0V$ | - | - | 1.2 | V |
| Continuous Source Current | I_S | - | - | - | 3.4 | A |

Notes:

1. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}=150^\circ\text{C}$.
2. The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper, The value in any given application depends on the user's specific board design.
3. Pulse Test: Pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$.
4. This value is guaranteed by design hence it is not included in the production test.

Electrical Characteristics P-Channel (T_J=25°C unless otherwise noted)

| Parameter | Symbol | Test Condition | Min. | Typ. | Max. | Unit |
|-----------------------------------------------|---------------------------|-----------------------------------------------------------------------------------------------|------|------|------|------|
| Static Characteristics | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | V _{GS} = 0V, I _D = -250μA | -30 | - | - | V |
| Gate-body Leakage Current | I_{GSS} | V _{DS} = 0V, V _{GS} = ±20V | - | - | ±100 | nA |
| Zero Gate Voltage Drain Current | I_{DSS} | V _{DS} = -30V, V _{GS} = 0V | - | - | -1 | μA |
| Gate Threshold Voltage | V_{GS(th)} | V _{DS} = V _{GS} , I _D = -250μA | -1 | -1.5 | -2 | V |
| Drain-Source On-state Resistance ³ | R_{DS(on)} | V _{GS} = -10V, I _D = -2.3A | - | 62 | 84 | mΩ |
| | | V _{GS} = -4.5V, I _D = -2A | - | 84 | 118 | |
| Dynamic Characteristics⁴ | | | | | | |
| Input Capacitance | C_{iss} | V _{GS} = 0V, V _{DS} = -15V, f = 1MHz | - | 345 | - | pF |
| Output Capacitance | C_{oss} | | - | 47 | - | |
| Reverse Transfer Capacitance | C_{rss} | | - | 35 | - | |
| Switching Characteristics⁴ | | | | | | |
| Total Ggate Charge | Q_g | V _{GS} = -10V, V _{DS} = -15V, I _D = -2.3A | - | 10.8 | - | nC |
| Gate-Source Charge | Q_{gs} | | - | 1.2 | - | |
| Gate-Drain Charge | Q_{gd} | | - | 1.3 | - | |
| Turn-On Delay Time | t_{d(on)} | V _{GS} = -10V, V _{DD} = -15V, I _D = -2.3A, R _G =3Ω | - | 13 | - | ns |
| Turn-On Rise Time | t_r | | - | 10 | - | |
| Turn-Off Delay Time | t_{d(off)} | | - | 28 | - | |
| Turn- Off Fall Time | t_f | | - | 13 | - | |
| Source-Drain Diode characteristics | | | | | | |
| Body Diode Voltage ³ | V_{DS} | I _S = -1A, V _{GS} = 0V | - | - | -1.2 | V |
| Continuous Source Current | I_S | - | - | - | -2.3 | A |

Notes:

1. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C.
2. The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper, The value in any given application depends on the user's specific board design.
3. Pulse Test: Pulse width≤300μs, duty cycle≤2%.
4. This value is guaranteed by design hence it is not included in the production test.

Typical Characteristics: N-Channel

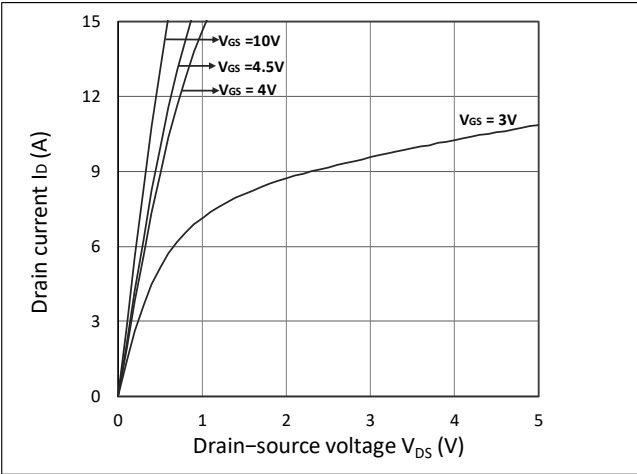


Figure 1. Output Characteristics

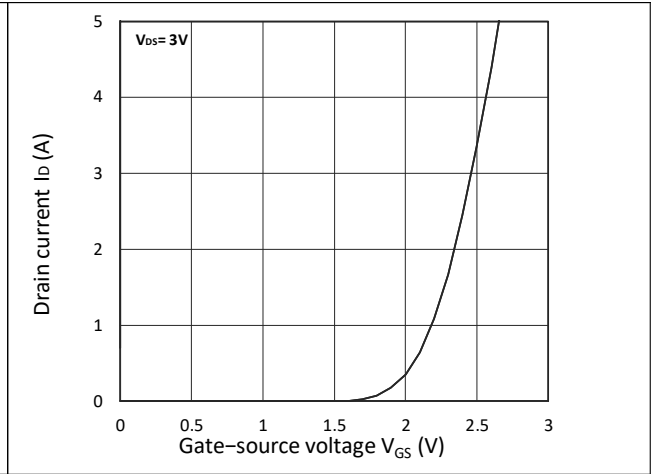


Figure 2. Transfer Characteristics

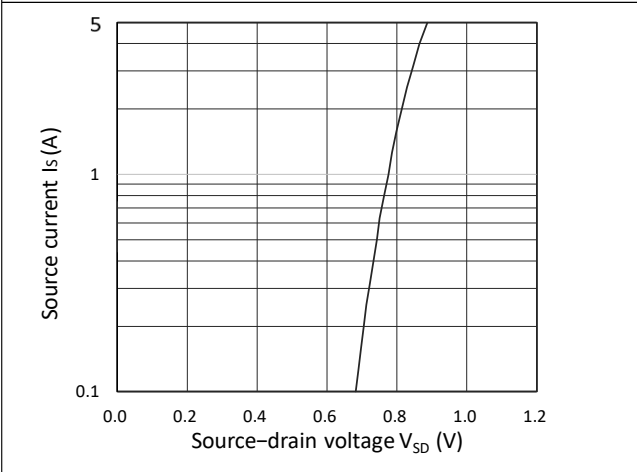


Figure 3. Forward Characteristics of Reverse

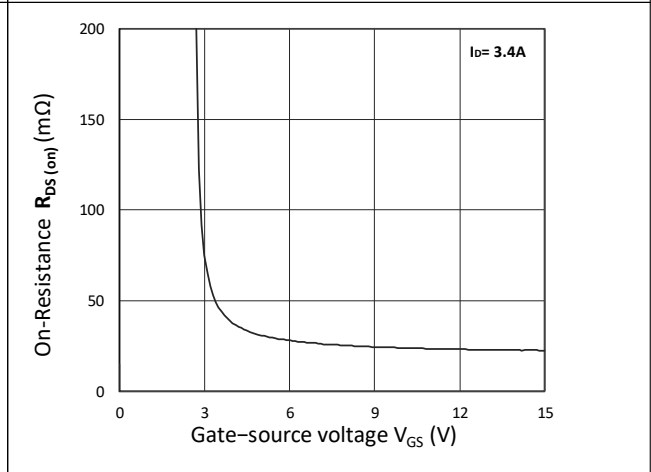


Figure 4. $R_{DS(ON)}$ vs. V_{GS}

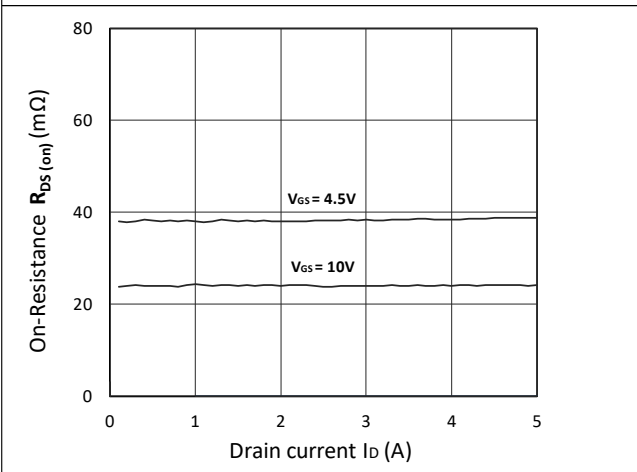


Figure 5. $R_{DS(ON)}$ vs. I_D

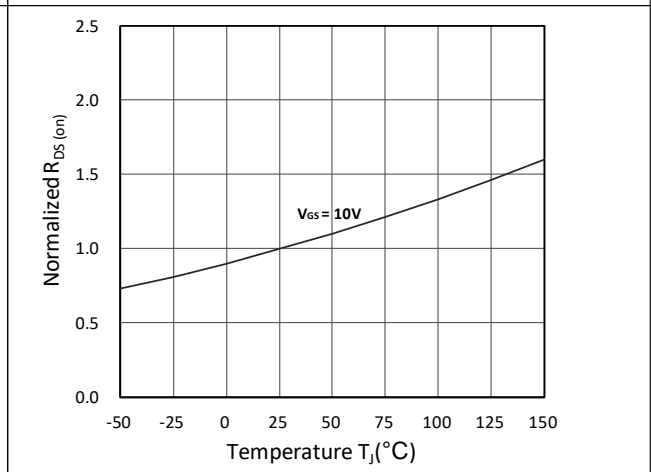
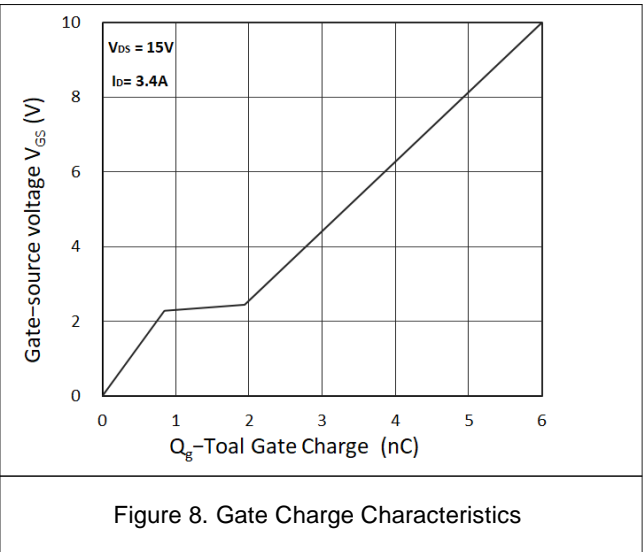
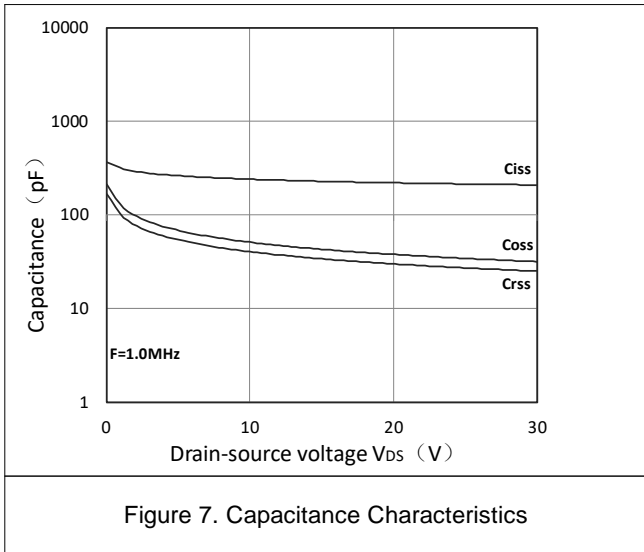


Figure 6. Normalized $R_{DS(ON)}$ vs. Temperature



Typical Characteristics: P-Channel

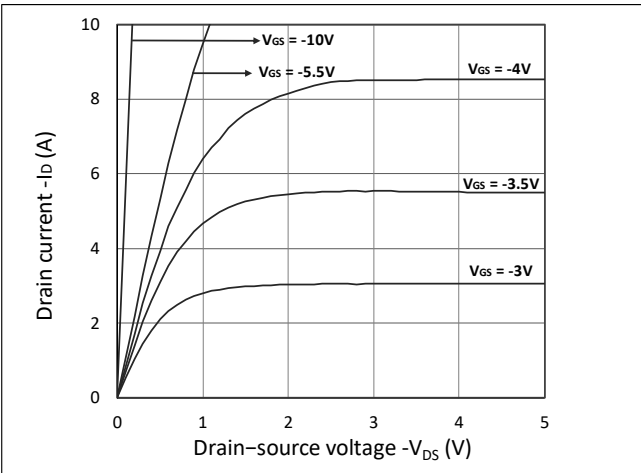


Figure 1. Output Characteristics

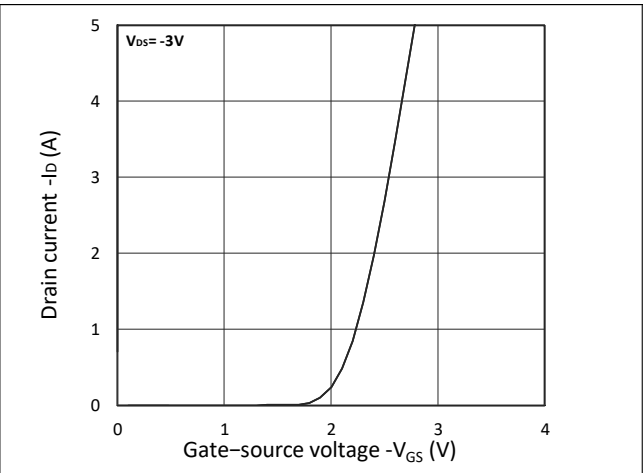


Figure 2. Transfer Characteristics

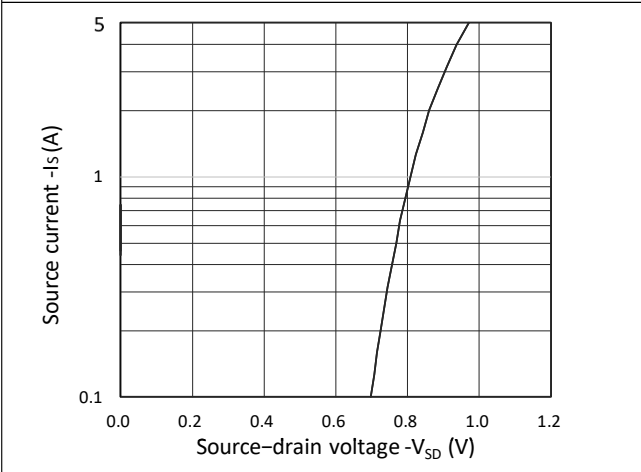


Figure 3. Forward Characteristics of Reverse

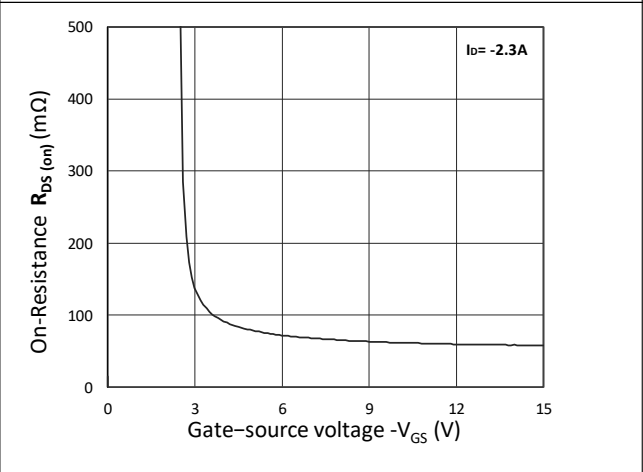


Figure 4. $R_{DS(on)}$ vs. V_{GS}

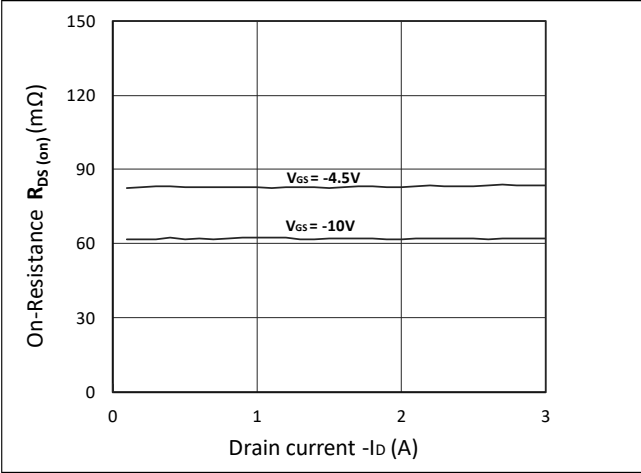


Figure 5. $R_{DS(on)}$ vs. I_D

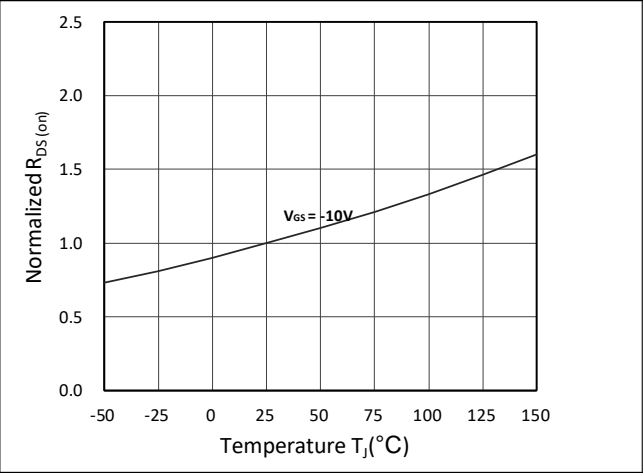


Figure 6. Normalized $R_{DS(on)}$ vs. Temperature

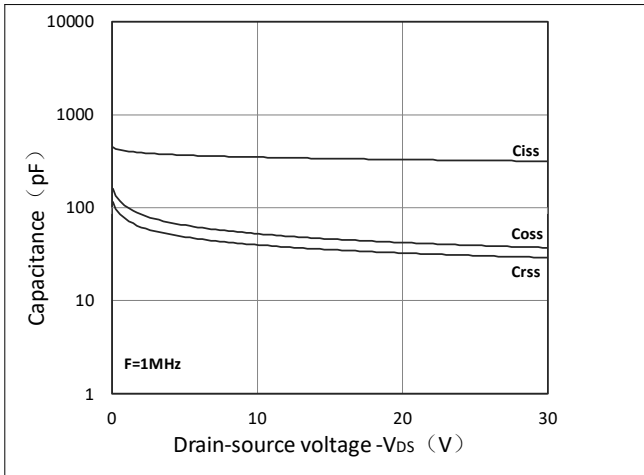


Figure 7. Capacitance Characteristics

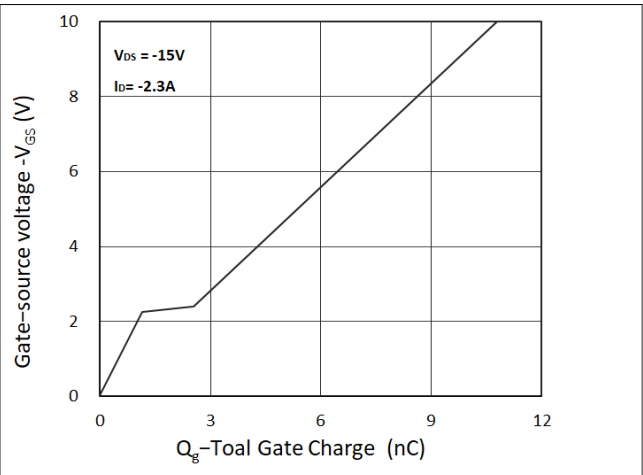
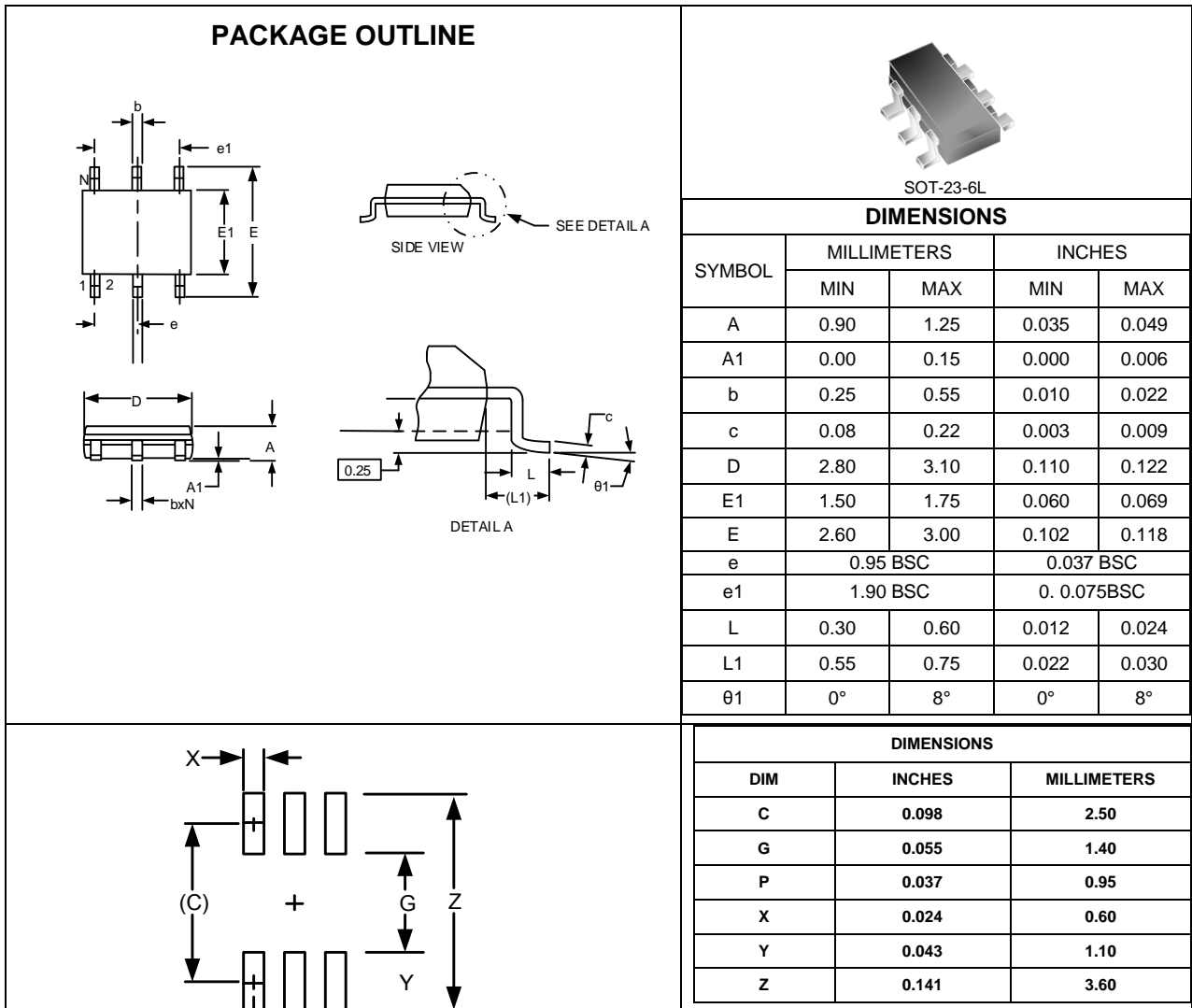


Figure 8. Gate Charge Characteristics

Outline Drawing – SOT-23-6L



Marking Codes

| | |
|--------------|------------|
| Part Number | WM03DH34M3 |
| Marking Code | |

Package Information

Qty: 3k/Reel

CONTACT INFORMATION

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WAYON website: <http://www.way-on.com>

For additional information, please contact your local Sales Representative.

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1. The product specification aims to provide users with a reference regarding various product parameters, performance, and usage. It presents certain aspects of the product's performance in graphical form and is intended solely for users to select product and make product comparisons, enabling users to better understand and evaluate the characteristics and advantages of the product. It does not constitute any commitment, warranty, or guarantee.
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